

Features

- V_{IN} Voltage: Support 2.5-V, 3.3-V and 5-V Power Rails
- V_{LDOIN} Voltage Range: 1.1 V to 3.5 V
- Flexible Input Voltage Tracking Directly from REFIN or through External Resistor Divider
- 3-A Sink and Source Current Capability for DDR Termination
- Integrated Power MOSFETs
- · Output Remote Sensing
- Fast Load-Transient Response
- Output Ramps Up in 35 µs
- Open-Drain Power Good to Monitor OUT Regulation
- Built-in Soft-Start and UVLO, Current Limit, and Thermal Shutdown Protection
- Support DDR, DDR2, DDR3, DDR3L, Low-Power DDR3 and DDR4 VTT Applications
- Operating Temperature Range: –40°C to +125°C
- Small Package with DFN3X3-10
- Pb-Free and RoHS Compliant

Applications

- Memory VTT Regulator for DDR, DDR2, DDR3, DDR3L, Low-Power DDR3 and DDR4
- · Notebooks, Desktops, and Workstations
- Servers, Networking Equipment, and Datacenters
- Telecom and Base Station

Description

With the development of main processors in PCs and servers, more and more source double-data-rate (DDR) memories are required in the mainboard, where the input voltage becomes lower and lower, and space limitation becomes higher and higher.

The TPL51201 is a series of 3-A sink and source DDR termination regulators specifically designed for DDR applications with heavy space limitations. The TPL51201 series implements a fast load-transient response and only requires a minimum output capacitance of 20 μ F.

The TPL51201 series supports a remote-sensing function and all power requirements for DDR VTT bus termination. In addition, the TPL51201 series provides an open-drain PG signal for VTT regulation indication and an EN signal that can be used to discharge VTT for DDR applications.

The TPL51201 series is available in the thermally efficient DFN3x3-10 package with a thermal pad, and supports the operating temperature range from -40°C to +125°C.

Typical Application Schematic

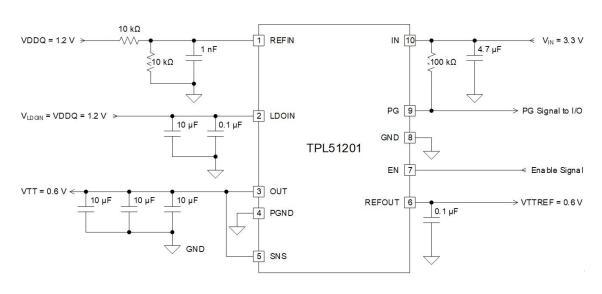




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Product Family Table

Part Number	Output Current	Orderable Number	Package	Transport Media, Quantity		Marking information
TPL51201G-S	3 A	TPL51201G- DF8R-S	DFN3×3-10	4,000	MSL3	L200

Revision History

Date	Revision	Notes
2020-11-23	Rev.Pre.0	Preliminary version
2021-05-31	Rev.A.0	Initial released
2021-09-30	Rev.A.1	Added more details of OUT and SNS Output Capacitor on Page 14
2024-11-04	Rev.A.2	Updated to a new datasheet format Corrected "V _{IN} " to "V _{LDOIN} " in the power dissipation calculation equation Updated Thermal Information

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Pin Configuration and Functions

TPL51201
DFN3X3-10 Package
Top View

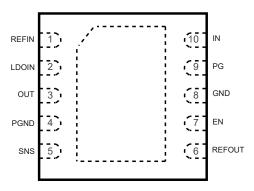


Table 1. Pin Functions: TPL51201

Р	in	I/O	Description				
No.	No. Name		Description				
7	EN	I	Regulator enable pin. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VDDQ directly.				
8	GND	-	Ground reference pin. Connect the GND pin to the PCB ground plane directly.				
10	IN	I	Regulator power supply input pin. A 1-µF or larger ceramic capacitor from IN to ground (as close as possible to the IN pin) is required to reduce the jitter from the previous-stage power supply.				
2	LDOIN	I	LDO power supply input pin.				
3	OUT	0	LDO output voltage pin. Total capacitance of 20-µF or larger from OUT to ground (as close as possible to the OUT pin) is required to ensure regulator stability.				
9	PG	0	Open-drain power-good output pin.				
4	PGND	_	Power ground pin. Connect the PGND pin to the PCB ground plane directly.				
1	REFIN	I	Reference input pin. For the DDR application, set to VDDQ/2 through a resistor divider.				
6	REFOUT	0	Reference output pin. Connect to GND through a 0.1-μF to 1-μF ceramic capacitor.				
5	SNS	I	LDO output voltage sense pin. Connect SNS to the remote DDR termination bypass capacitors to get accurate remote feedback sensing of OUT voltage.				

⁽¹⁾ Exposed PAD must be connected to a large-area ground plane to maximize the thermal performance.

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Specifications

Absolute Maximum Ratings

Parameters		Min	Max	Unit
EN, IN, LDOIN, PG, RE	FIN, SNS	-0.3	6	V
PGND to GND		-0.3	0.3	V
OUT, REFOUT		-0.3	3.6	V
TJ	Junction Temperature Range	-40	150	°C
T _{STG}	Storage Temperature Range	-55	150	°C
TL	Lead Temperature (Soldering 10 sec)		260	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

ESD, Electrostatic Discharge Protection

Symbol	Parameter	Condition	Minimum Level	Unit
НВМ	Human Body Model ESD	ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
CDM	Charged Device Model ESD	ANSI/ESDA/JEDEC JS-002 (2)	±1500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

Recommended Operating Conditions

	Parameter	Min	Тур	Max	Unit
IN	Regulator Input Voltage	2.375		5.5	V
LDOIN	LDO Input Voltage	-0.1		3.5	V
EN	Regulator Enable Voltage	-0.1		3.5	V
OUT	LDO Output Voltage	-0.1		3.5	V
SNS	LDO Output Sense Voltage	-0.1		3.5	V
REFIN	Reference Input Voltage	0.5		1.8	V
REFOUT	Reference Output Voltage	-0.1		1.8	V
PG	Power-Good Pull-up Voltage	-0.1		3.5	V
PGND	Power Ground Voltage to GND	-0.1		0.1	V
T_J	Junction Temperature Range	-40		125	°C

Thermal Information

Package	ΑLΘ	Ө ЈВ	Ө ЈС,ТОР	Unit
DFN3x3-10	42.07	10.08	75.14	°C/W

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⁽²⁾ All voltage values are with respect to GND.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



Electrical Characteristics

All test conditions: $T_J = -40$ °C to +125°C (typical value at $T_J = +25$ °C), $V_{IN} = V_{EN} = 3.3$ V, $V_{LDOIN} = 1.8$ V, $V_{REFIN} = 0.9$ V, $V_{SNS} = 0.9$ V, $V_{IN} = 10$ μ F, and $V_{IN} = 10$ μ F, and $V_{IN} = 10$ μ F, unless otherwise noted.

	Parameter	Conditions	Min	Тур	Max	Unit
Supply In	out Voltage and Current					
VIN	Input Supply Voltage Range		2.375		5.5	V
V _{LDOIN}	LDO Input Voltage Range				3.5	V
1040	Input Supply UVLO	T _A = +25°C, V _{IN} Rising		2.3	2.375	V
UVLO _{IN}	Hysteresis			50		mV
I _{IN}	Input Supply Current of IN	T _A = +25°C, V _{EN} = 3.3 V, I _{OUT} = 0 mA		0.8	1	mA
I _{IN_SD}	Shutdown Current of IN	T_A = +25°C, V_{EN} = 0 V, V_{REFIN} = 0 V, I_{OUT} = 0 mA		65	80	μΑ
		T _A = +25°C, V _{EN} = 0 V, V _{REFIN} > 0.4 V, I _{OUT} = 0 mA		200	400	μΑ
I _{LDOIN}	Input Current of LDOIN	T _A = +25°C, V _{EN} = 3.3 V, I _{OUT} = 0 mA		1	50	μΑ
I _{LDOIN_SD}	Shutdown Current of LDOIN	T _A = +25°C, V _{EN} = 0 V, I _{OUT} = 0 mA		1	50	μΑ
Reference	Input and Output					
V _{REFIN}	Reference Input voltage		0.5		1.8	V
UVLO _{REFI}	Reference Input UVLO	T _A = +25°C, V _{REFIN} Rising	360	390	420	mV
N	Hysteresis			20		mV
I _{REFIN}	Input Current of REFIN	V _{EN} = 3.3 V		1		μΑ
V_{REFOUT}	Reference Output Voltage			V _{REFIN}		V
V _{REFOUT_T}		-1 mA ≤ I _{REFOUT} ≤ 1 mA, 0.5 V ≤ V _{REFIN} ≤ 1.8 V	-12		12	mV
OL	Tolerance of REFOUT to REFIN	-10 mA ≤ I _{REFOUT} ≤ 10 mA, 0.5 V ≤ V _{REFIN} ≤ 1.8 V	-15		15	mV
I _{REFOUT_SR}	Source Current Limit of REFOUT	V _{REFOUT} = 0.5 V	10	60		mA
I _{REFOUT_SN}	Sink Current Limit of REFOUT	V _{REFOUT} = 1.5 V	10	60		mA
Regulated	Output Voltage and Current					
		V _{REFOUT} = 1.25 V (DDR1), I _{OUT} = 0 A		1.25		V
V_{OUT}	Output Voltage	Tolerance	-15		15	mV
		V _{REFOUT} = 0.9 V (DDR2), I _{OUT} = 0 A		0.9		V

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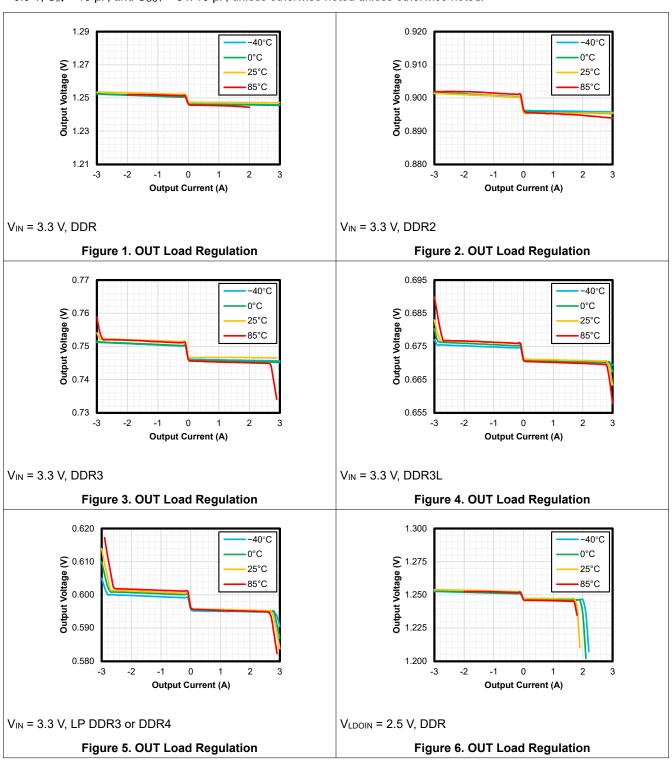


Parameter		Conditions	Min	Тур	Max	Unit
		Tolerance	-15		15	mV
		$V_{REFOUT} = 0.75 \text{ V (DDR3)},$ $I_{OUT} = 0 \text{ A}$		0.75		V
		Tolerance	-15		15	mV
		$V_{REFOUT} = 0.675 \text{ V (DDR3L)},$ $I_{OUT} = 0 \text{ A}$		0.675		V
		Tolerance	-15		15	mV
		V _{REFOUT} = 0.6 V (DDR4), I _{OUT} = 0 A		0.6		V
		Tolerance	-15		15	mV
ΔV_{OUT}	Tolerance of OUT to REFOUT	-2 A < I _{OUT} < 2 A	-25		25	mV
lout_srcl	Source Current Limit of OUT	V _{SNS} = 90% × V _{REFOUT}	3		4.5	Α
I _{OUT_SNKL}	Sink Current Limit of OUT	V _{SNS} = 110% × V _{REFOUT}	3.2		5.5	Α
R _{DIS}	Discharge Resistance	$T_A = +25$ °C, $V_{REFIN} = 0 \text{ V}$, $V_{OUT} = 0.3 \text{ V}$, $V_{EN} = 0 \text{ V}$		12		Ω
Enable Co	ontrol					
	EN High-Level Input Voltage	Device Enable	1.7			V
V _{EN}	EN Low-Level Input Voltage of	Device Disable			0.5	V
	Hysteresis			0.25		V
I _{EN}	Leakage Current of EN	$T_A = +25$ °C, $V_{EN} = 0$ V to 6.5 V	-1		1	μΑ
Power Go	od					
	PG Lower Threshold	With Respect to REFOUT	-23.5%	-20%	-17.5%	
V_{PG}	PG Upper Threshold	With Respect to REFOUT	17.5%	20%	23.5%	
	Hysteresis			5%		
I PG	Leakage Current of PG				1	μΑ
V _{OL(PG)}	PG Low-Level Output Voltage	Source 4 mA to PG pin			0.4	V
t _{DLY(PG)}	PG Start-up Delay	Startup Rising edge, V _{SNS} within 15% of V _{REFOUT}		2		ms
t _{DLY(PG_B)}	PG Start-up Bad Delay	V _{SNS} is Beyond the ±20% PG Trip Threshold		10		μs
Temperatu	ire Range					
	Thermal Shutdown Threshold	Temperature Increasing		155		°C
T _{SD}	Hysteresis			25		°C
TJ	Operating junction Temperature		-40		125	°C



Typical Performance Characteristics

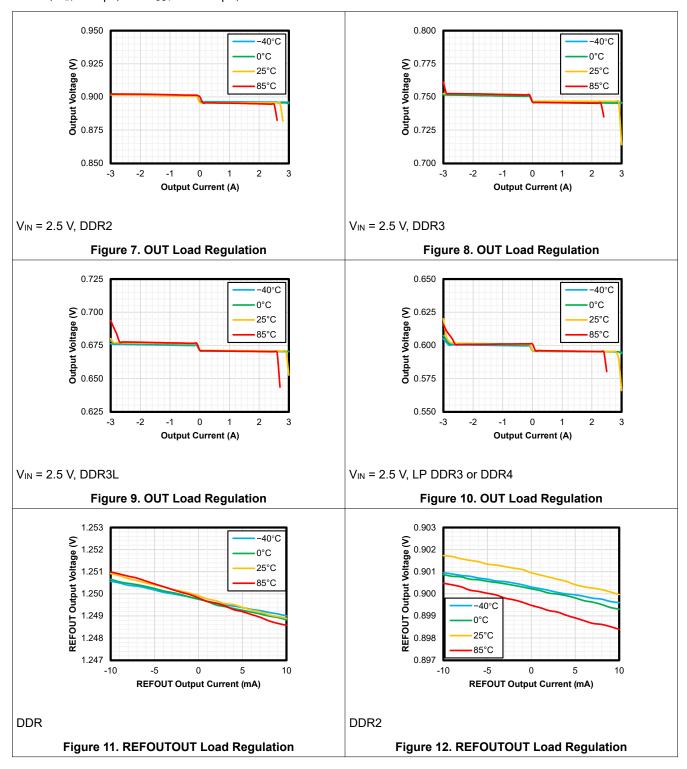
All test conditions: $T_J = -40^{\circ}\text{C}$ to +125°C (typical value at $T_J = +25^{\circ}\text{C}$), $V_{IN} = V_{EN} = 3.3 \text{ V}$; $V_{LDOIN} = 1.8 \text{ V}$, $V_{REFIN} = 0.9 \text{ V}$, $V_{SNS} = 0.9 \text{ V}$, $C_{IN} = 10 \text{ }\mu\text{F}$, and $C_{OUT} = 3 \text{ x}$ 10 μF , unless otherwise noted unless otherwise noted.





Typical Performance Characteristics (continued)

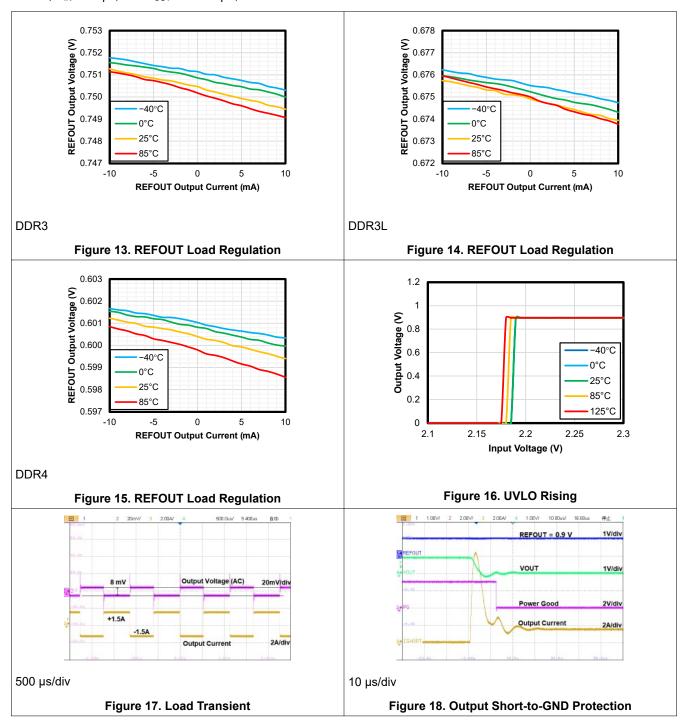
All test conditions: $T_J = -40$ °C to +125°C (typical value at $T_J = +25$ °C), $V_{IN} = V_{EN} = 3.3$ V; $V_{LDOIN} = 1.8$ V, $V_{REFIN} = 0.9$ V, $V_{SNS} = 0.9$ V, $V_{IN} = 10$ μ F, and $V_{COIT} = 3$ x 10 μ F; unless otherwise noted unless otherwise noted.





Typical Performance Characteristics (continued)

All test conditions: $T_J = -40$ °C to +125°C (typical value at $T_J = +25$ °C), $V_{IN} = V_{EN} = 3.3$ V; $V_{LDOIN} = 1.8$ V, $V_{REFIN} = 0.9$ V, $V_{SNS} = 0.9$ V, $V_{IN} = 10$ μ F, and $V_{COIT} = 3$ x 10 μ F; unless otherwise noted unless otherwise noted.



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Detailed Description

Overview

The TPL51201 is a series of 3-A sink and source DDR termination regulators specifically designed for DDR applications with heavy space limitations. The TPL51201 series implements a fast load-transient response and only requires a minimum output capacitance of $20 \, \mu F$.

The TPL51201 series supports a remote-sensing function and meets all power requirements for DDR VTT bus termination. In addition, the TPL51201 series provides an open-drain PG signal for VTT regulation indication, and an EN signal that can be used to discharge VTT for DDR1 to DDR4 applications.

Functional Block Diagram

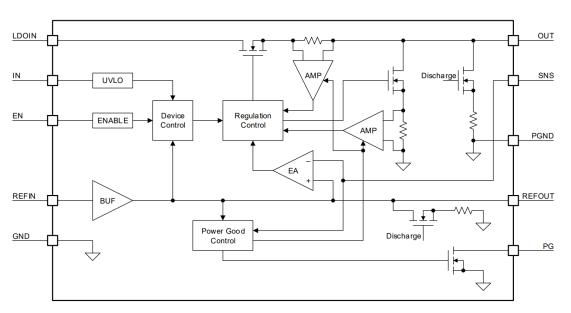


Figure 19. Functional Block Diagram

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Feature Description

Sink and Source Regulator (OUT and SNS)

The TPL51201 is a series of 3-A sink and source DDR termination regulators specifically designed for DDR applications with heavy space limitations. The TPL51201 series integrates a high-performance, low-dropout linear regulator with a fast-feedback loop that can support fast load transient response with small ceramic capacitors. To get tight regulation tolerance, the remote sensing pin, the SNS pin, must be connected to the OUT pin through a separate trace from the high current path.

Voltage Reference (REFIN and REFOUT)

The TPL51201 series uses the voltage at the REFIN pin as the reference voltage, and the output voltage at the REFOUT pin exactly follows the REFIN voltage within the tolerance of VREFOUT_TOL. When the TPL51201 series is configured for standard DDR applications, the voltage at the REFIN pin is divided through an external voltage divider from the DDR supply bus, VDDQ. The TPL51201 series supports the REFIN input voltage range from 0.5 V to 1.8 V. When the REFIN voltage is higher than the rising UVLO threshold of REFIN and IN voltage is ready, there is voltage regulated at the REFOUT pin, which the REFOUT pin is independent with EN status.

Enable Control (EN)

The TPL51201 series integrates the high-active device enabling the control feature. Connect this pin to the GPIO of an external processor or digital logic control circuit to enable and disable the device.

Under-voltage Lockout (IN UVLO)

The TPL51201 series uses an under-voltage lockout circuit to keep the regulator shut off until the IN voltage exceeds the rising UVLO threshold of IN.

Power-Good Indicator (PG)

The TPL51201 series integrates an open-drain output power good indicator. After regulator startup, the PG pin keeps low impendence until the output voltage enters the power-good window, $\pm 20\%$ of REFOUT voltage. When output voltage enters the power-good window, the PG pin turns to high output impedance, and PG is pulled up to a high-voltage level after a 2-ms delay indicating the output voltage is ready. It is recommended to connect a 100-k Ω pull-up resistor between the PG pin and the pull-up voltage supply.

Over-Current Protection

The TPL51201 series integrates constant over-current protection. When the output voltage exists in the power-good window, ±20% of REFOUT voltage, the current-limit level reduces 50% of the full level. After the output voltage enters the power-good window, the current-limit level is released to the full level.

Over-Temperature Protection

The recommended operating junction temperature range is from -40°C to 125°C . When the junction temperature is between 125°C and the thermal shutdown (TSD) threshold, the regulator can still work well, but the lifetime of the device for long-term use is reduced. The over-temperature protection works when the junction temperature exceeds the thermal shutdown (TSD) threshold, which turns off the regulator immediately. When the device cools down and the junction temperature falls below the thermal shutdown threshold minus thermal shutdown hysteresis, the regulator turns on again.

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Application and Implementation

Note

Information in the following application sections is not part of the 3PEAK's component specification and 3PEAK does not warrant its accuracy or completeness. 3PEAK's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

Application Information

The TPL51201 is a series of 3-A sink and source DDR termination regulators specifically designed for DDR applications. The following application schematic shows a typical usage of the TPL51201 series.

Typical Application

Adjustable Output Operation

Figure 20 shows the typical application schematic of the TPL51201 series in DDR4 applications.

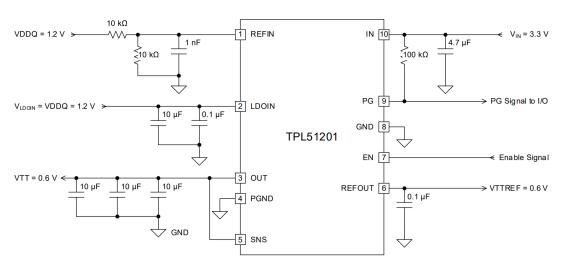


Figure 20. Typical Application Schematic

IN Input Capacitor

3PEAK recommends placing a 1-μF or greater capacitor with a 0.1-μF bypass capacitor in parallel close to the IN pin to keep the input voltage stable. The voltage rating of the capacitors must be greater than the maximum input voltage.

LDOIN Input Capacitor

3PEAK recommends placing a 10-μF or greater capacitor with a 0.1-μF bypass capacitor in parallel close to the LDOIN pin to keep the voltage stable during transient. More input capacitors are required if large output capacitors are used at the OUT pin. It is suggested to place input capacitors with half of the output capacitance value at the LDOIN pin.

OUT and SNS Output Capacitor

To ensure stable operation, the TPL51201 series requires output capacitors of 20 μ F or greater. 3PEAK recommends selecting three 10- μ F X5R-or X7R-type ceramic capacitors in parallel to minimize the equivalent series resistance (ESR) and

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equivalent series inductance (ESL). The output capacitors must be placed as close to the OUT pin as possible. When using the remote sense function, to prevent the instability issue caused by parasitic parameters of the long output power trace, it is recommended to keep the total capacitance of C_{OUT} between 10 μ F and 30 μ F, and the total capacitance of the remote DDR termination bypass capacitors should be greater than that of 3 × C_{OUT} .

Application Waveform

All test conditions: $V_{IN} = V_{EN} = 3.3 \text{ V}$; $V_{LDOIN} = 1.2 \text{ V}$, $V_{REFIN} = 0.6 \text{ V}$, $I_{OUT} = 1 \text{ A}$, $C_{IN} = 10 \text{ }\mu\text{F}$, and $C_{OUT} = 3 \text{ x}$ 10 μF .

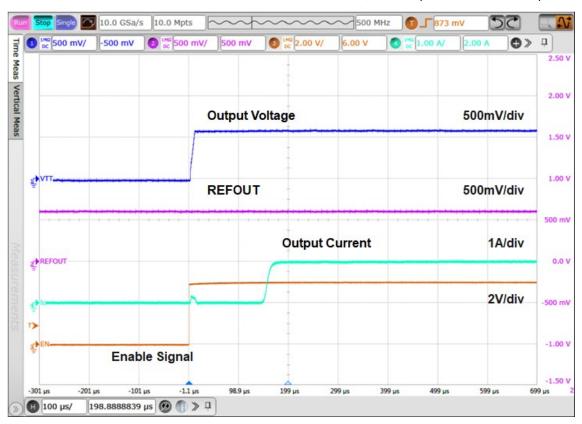


Figure 21. Output Voltage Startup Waveform

Power Dissipation

During normal operation, the LDO junction temperature should not exceed 125°C. Use the below equations to calculate the power dissipation and estimate the junction temperature.

The power dissipation can be calculated using Equation 1.

$$P_{D} = (V_{LDOIN} - V_{OUT}) \times I_{OUT} + V_{LDOIN} \times I_{GND}$$
(1)

The junction temperature can be estimated using Equation 2. θ_{JA} is the junction-to-ambient thermal resistance.

$$T_{J} = T_{A} + P_{D} \times \theta_{JA} \tag{2}$$

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Layout

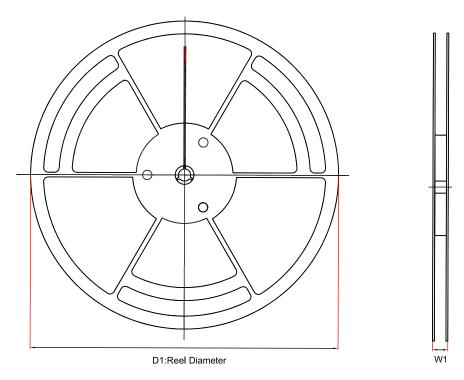
Layout Guidelines

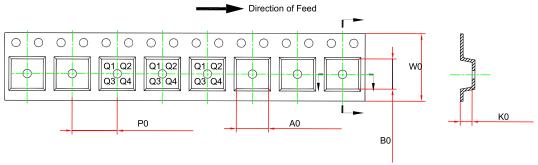
- Both input and output capacitors must be placed as close to the device pins as possible.
- Suggest bypassing the input pin to ground with a 0.1-µF bypass capacitor. The loop area formed by the bypass capacitor connection, voltage input pin, and the ground pin of the system must be as small as possible.
- Suggest using wide and thick copper to minimize I×R drop and heat dissipation.
- The GND pin and the PGND pin must be connected to the thermal pad with multiple thermal vias as many as possible connected to the internal ground planes.

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Tape and Reel Information





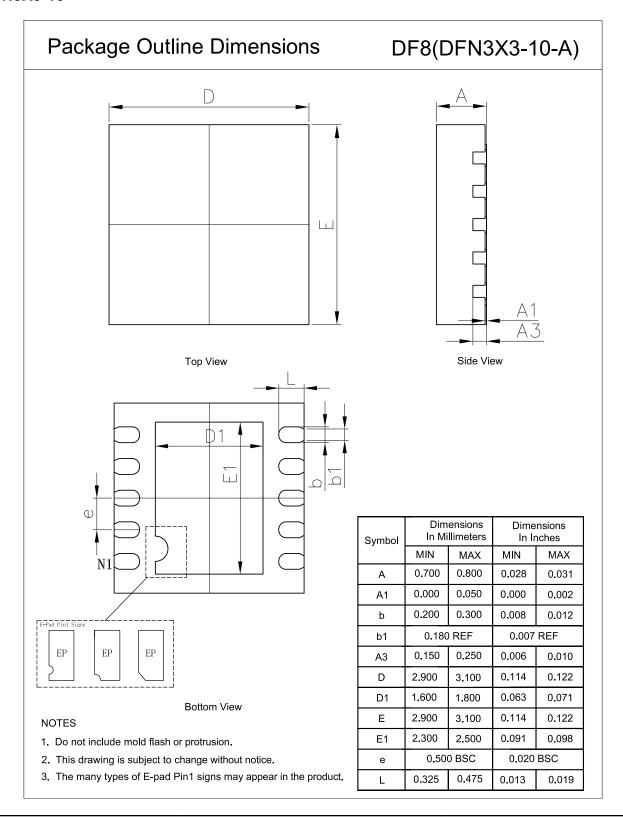
Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	W0 (mm)	Pin1 Quadrant
TPL51201G- DF8R-S	DFN3x3-10	330	17.6	3.3	3.3	1.1	8	12	Q2

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Package Outline Dimensions

DFN3X3-10





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